

# PATENT APPLICATION COVER SHEET

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**25700**

PATENT TRADEMARK OFFICE

22388 U.S. PTO  
10/678445  
100303

Sir/Madam:

Transmitted herewith is the patent application of:

Inventor(s): George Jonathan Kluth, Joong S. Jeon, Qi Xiang and Huicai Zhong

For: "Method for Forming Polysilicon Gate on High-K Dielectric and Related Structure"

☐ This application is a ☐ Continuation ☐ Divisional ☐ Continuation-in-part (CIP) of prior application No.: \_\_\_\_\_.

Enclosed are:

- ☒ Three (3) Sheets of drawings
- ☒ Request for Non-Publication (Form PTO/SB/35 (11-00))
- ☒ An assignment of the invention to Advanced Micro Devices, Inc.
- ☒ The enclosed payment includes \$40.00 for the recording of the assignment
- ☐ Applicant(s) claim(s) small entity status
- ☐ Information Disclosure Statement
- ☐ Preliminary Amendment
- ☒ Declaration and Power of Attorney
- ☒ The filing fee has been calculated as shown below:

	(Col. 1)	(Col. 2)
FOR:	No. Filed	No. Extra
BASIC FEE		
TOTAL CLAIMS	20 -20 =	0
INDEPENDENT CLAIMS	3 -3 =	0
MULTIPLE DEPENDENT CLAIMS PRESENTED		

If the difference in Col. 1 is less than zero,  
enter "0" in Col. 2

## SMALL ENTITY

RATE	FEE
	\$385.00
x 9 =	\$
x 43 =	\$
+145 =	\$
<b>TOTAL</b>	<b>\$</b>

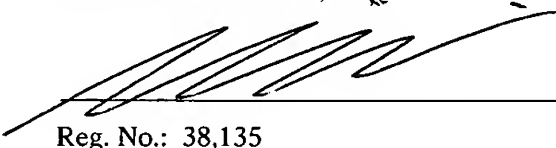
## OTHER THAN A SMALL ENTITY

RATE	FEE
	\$770.00
x 86 =	\$0.00
x 86 =	\$0.00
+290 =	\$
<b>TOTAL</b>	<b>\$770.00</b>

- ☒ Enclosed is a payment in the amount of \$810.00 by credit card (Form PTO-2038 attached).
- ☐ Please charge Deposit Account No. 50-0731 in the amount of \$ \_\_\_\_.
- ☒ The Commissioner is hereby authorized to charge payment of any additional fees associated with this communication, or credit any overpayment to Deposit Account No. 50-0731. A duplicate copy of this sheet is enclosed.

MICHAEL FARJAMI, ESQ.

Date: 10/3/03

  
Reg. No.: 38,135




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Michael Farjami, Esq.  
FARJAMI & FARJAMI LLP  
16148 Sand Canyon  
Irvine, CA 92618  
(949) 784-4600

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Date of Deposit 10/3/03

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<b>NONPUBLICATION REQUEST UNDER 35 U.S.C. 122(b)(2)(B)(i)</b>	First Named Inventor	Kluth, et al.
	Title	Method for Forming Polysilicon Gate on High-K Dielectric and Related Structure
	Atty Docket Number	0180146

I hereby certify that the invention disclosed in the attached application **has not and will not be** the subject of an application filed in another country, or under a multilateral agreement, that requires publication at eighteen months after filing.

I hereby request that the attached application not be published under 35 U.S.C. 122(b).

10/3/03  
Date

  
Signature

Michael Farjami, Esq.  
Typed or printed name

This request must be signed in compliance with 37 CFR 1.33(b) and submitted with the application **upon filing**.

Applicant may rescind this nonpublication request at any time. If applicant rescinds a request that an application not be published under 35 U.S.C. 122(b), the application will be scheduled for publication at eighteen months from the earliest claimed filing date for which a benefit is claimed.

If applicant subsequently files an application directed to the invention disclosed in the attached application in another country, or under a multilateral international agreement, that requires publication of applications eighteen months after filing, the applicant **must** notify the United States Patent and Trademark Office of such filing within forty-five (45) days after the date of the filing of such foreign or international application. **Failure to do so will result in abandonment of this application (35 U.S.C. 122(b)(2)(B)(iii)).**

**Burden Hour Statement:** This collection of information is required by 37 CFR 1.213(a). The information is used by the public to request that an application not be published under 35 U.S.C. 122(b) (and the PTO to process that request). Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This form is estimated to take 6 minutes to complete. This time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, U.S. Patent Trademark Office, Washington, DC 20231. **DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.**